

6-Pin DIP Phototransistor Optocouplers

H11AG1M

Description

The H11AG1M device consists of a Gallium-Aluminum- Arsenide IRED emitting diode coupled with a silicon phototransistor in a dual in-line package. This device provides the unique feature of high current transfer ratio at both low output voltage and low input current. This makes it ideal for use in low-power logic circuits, telecommunications equipment and portable electronics isolation applications.

Features

- High-Efficiency Low-Degradation Liquid Epitaxial I_{RED}
- Logic Level Compatible, Input and Output Currents, with CMOS and LS/TTL
- High DC Current Transfer Ratio at Low Input Currents (as low as 200 μA)
- Safety and Regulatory Approvals:
 - ◆ UL1577, 4,170 VAC_{RMS} for 1 Minute
 - DIN-EN/IEC60747-5-5, 850 V Peak Working Insulation Voltage
- These are Pb-Free Devices

Applications

- CMOS Driven Solid State Reliability
- Telephone Ring Detector
- Digital Logic Isolation

SCHEMATIC

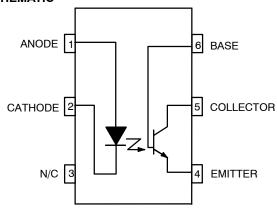


Figure 1. Schematic







PDIP6 CASE 646BX

PDIP6 CASE 646BZ

MARKING DIAGRAM



H11AG1 = Device Number

V = DIN EN/IEC60747-5-5 Option (only appears on component ordered

with this option) = One-Digit Year Code

YY = Digit Work Week
Q = Assembly Package Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

SAFETY AND INSULATION RATINGS

Parameter		Characteristic
Installation Classifications per DIN VDE	< 150 V _{RMS}	I – IV
0110/1.89 Table 1, For Rated Mains Voltage	< 300 V _{RMS}	I – IV
Climatic Classification	55/100/21	
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V _{PR}	Input–to–Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10$ s, Partial Discharge < 5 pC	1360	V _{peak}
	Input–to–Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC	1594	V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	850	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	6000	V _{peak}
	External Creepage	≥7	mm
	External Clearance	≥7	mm
	External Clearance (for Option TV, 0.4" Lead Spacing)	≥ 10	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.5	mm
T _S	Case Temperature (Note 1)	175	°C
I _{S,INPUT}	Input Current (Note 1)	350	mA
P _{S,OUTPUT}	Output Power (Note 1)	800	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V (Note 1)	> 10 ⁹	Ω

As per DIN EN/IEC 60747–5–5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
TOTAL DEV	/ICE		
T _{STG}	Storage Temperature	-40 to +125	°C
T _{OPR}	Operating Temperature	-40 to +100	°C
T_J	Junction Temperature	-40 to +125	°C
T _{SOL}	Lead Solder Temperature	260 for 10 s	°C
P_{D}	Total Device Power Dissipation @ 25°C(LED plus detector)	225	mW
	Derate Linearly From 25°C	3.5	mW/°C
EMITTER			
I _F	Continuous Forward Current	50	mA
V_{R}	Reverse Voltage	6.0	W
I _F (pk)	Forward Current – Peak (1 µs pulse 300 pps)	3.0	Α
P_{D}	Led Power Dissipation @T _A = 25°C	75	mW
	Derate Linearly From 25°C	1.0	mW/°C
DETECTOR	1		
I _C	Continuous Collector Current	50	mA
P_{D}	Total Power Dissipation @T _A = 25°C	150	mW
	Derate Linearly From 25°C	2.0	mW/°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

^{1.} Safety limit values – maximum values allowed in the event of a failure.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise specified})$

INDIVIDUAL COMPONENT CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit		
EMITTER	EMITTER							
V _F	Input Forward Voltage	I _F = 1 mA	-	1.25	1.50	V		
I _R	Reverse Leakage Current	V _R = 5 V, T _A = 25°C	-	-	10	μΑ		
CJ	Capacitance	V _F = 0 V, f = 1.0 MHz	-	-	100	pF		
DETECTOR	3							
BV _{CEO}	Breakdown Voltage, Collector-to-Emitter	I _C = 1 mA, I _F = 0	30	-	-	V		
BV _{CBO}	Breakdown Voltage, Collector-to-Base	$I_C = 100 \mu A, I_F = 0$	70	-	-	V		
BV _{ECO}	Breakdown Voltage, Emitter-to-Collector	$I_C = 100 \mu A, I_F = 0$	7	-	-	V		
I _{CEO}	Leakage Current, Collector-to-Emitter	V _{CE} = 10 V, I _F = 0	_	5	10	nA		
C _{CE}	Capacitance	V _{CE} = 10 V, f = 1 MHz	-	10	-	pF		

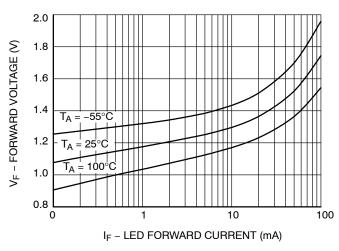
TRANSFER CHARACTERISTICS

Symbol	Characteristics	Test Conditions	Min.	Тур.	Max.	Unit		
DC CHARA	DC CHARACTERISTICS							
CTR	Current Transfer Ratio	I _F = 1 mA, V _{CE} = 5 V	300	-	-	%		
		I _F = 1 mA, V _{CE} = 0.6 V	100	-	-	%		
		I _F = 0.2 mA, V _{CE} = 1.5 V	100	-	-	%		
V _{CE(SAT)}	Saturation Voltage	$I_C = 2.0 \text{ mA}, I_F = 0.5 \text{ mA}$	-	_	0.40	V		
AC CHARACTERISTICS (NON-SATURATED SWITCHING TIMES)								
t _{on}	Turn-On Time	R_L = 100 Ω , I_F = 1 mA, V_{CC} = 5 V	-	5	-	μs		
t _{off}	Turn-Off Time	RL = 100 Ω , I _F = 1 mA, V _{CC} = 5 V	-	5	-	μs		

ISOLATION CHARACTERISTICS

Symbol	Characteristics	Test Conditions	Min.	Тур.	Max.	Unit
V _{ISO}	Input-Output Isolation Voltage	t = 1 Minute	4170	-	-	VAC_{RMS}
C _{ISO}	Isolation Capacitance	V _{I-O} = 0 V, f = 1 MHz	-	0.2	1	pF
R _{ISO}	Isolation Resistance	$V_{I-O} = \pm 500 \text{ VDC}, T_A = 25^{\circ}\text{C}$	10 ¹¹	-	ı	Ω

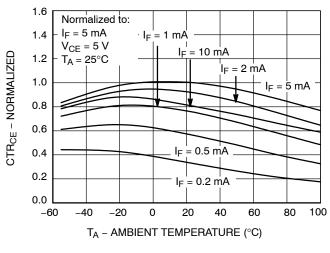
TYPICAL PERFORMANCE CHARACTERISTICS



1.2
1.0
0.8
0.6
0.6
0.2
0.1
1
1
1
1
1
10
100
IF - LED FORWARD CURRENT (mA)

Figure 2. LED Forward Voltage vs. Forward Current

Figure 3. Normalized Current Transfer Ratio vs. Forward Current



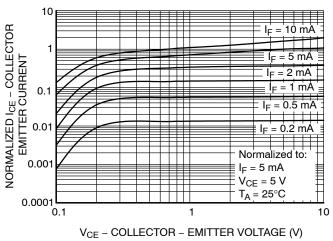
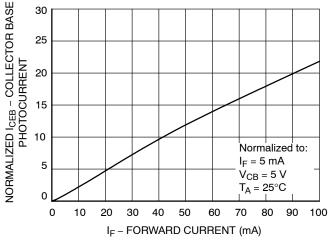
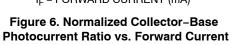


Figure 4. Normalized CTR vs. Temperat

Figure 5. Normalized Collector vs. Collector-Emitter Voltage





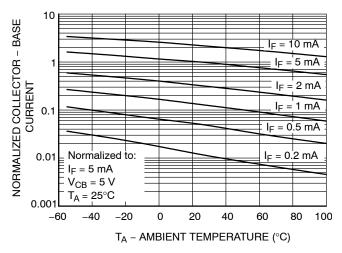


Figure 7. Normalized Collector-Base Current vs. Temperature

TYPICAL PERFORMANCE CURVES (continued)

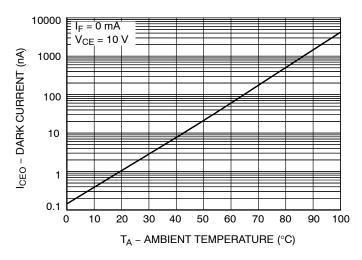
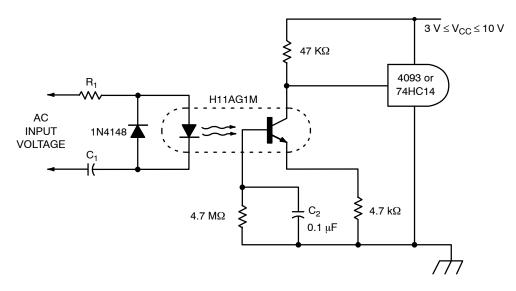


Figure 8. Collector–Emitter Dark Current vs.
Ambient Temperature

TYPICAL APPLICATION



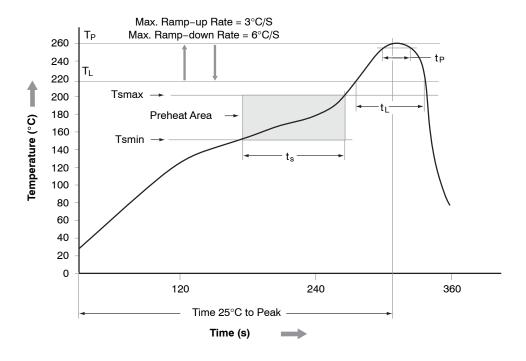
Input	R1	C1	Z
40 – 90 VAC _{RMS}	75 kΩ	0.1 μF	109 kΩ
20 Hz	1/10 W	100 V	
95 – 135 VAC _{RMS}	180 kΩ	12 nF	285 kΩ
60 Hz	1/10 W	200 V	
200 – 280 VAC _{RMS}	390 kΩ	6.80 nF	550 kΩ
50 / 60 Hz	1/4 W	400 V	

DC component of input voltage is ignored due to C1

The H11AG1M uses less input power than the neon bulb traditionally used to monitor telephone and line voltages. Additionally response time can be tailored to ignore telephone dial tap, switching transients and other undesired signals by modifying the value of C2. The high impedance to line voltage also can simply board layout spacing requirements.

Figure 9. Telephone Ring Detector / A.C. Line CMOS Input Isolator

REFLOW PROFILE



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t _S) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60-150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

Figure 10. Reflow Profile

ORDERING INFORMATION

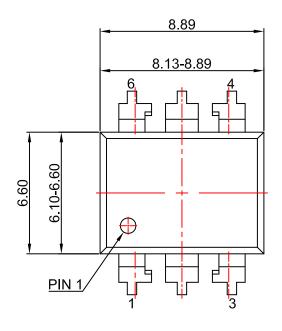
Part Number	Package	Shipping [†]
H11AG1M	DIP 6-Pin	50 Units / Tube
H11AG1SM	SMT 6-Pin (Lead Bend)	50 Units / Tube
H11AG1SR2M	SMT 6-Pin (Lead Bend)	1000 Units / Tape & Reel
H11AG1VM	DIP 6-Pin, DIN EN/IEC60747-5-5 Option	50 Units / Tube
H11AG1SVM	SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option	50 Units / Tube
H11AG1SR2VM	SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option	1000 Units / Tape & Reel
H11AG1TVM	DIP 6-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 Option	50 Units / Tube

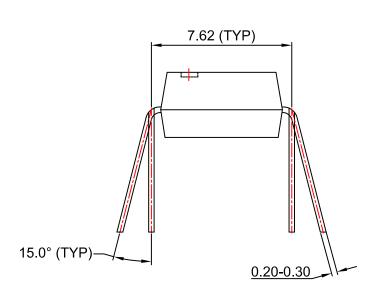
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

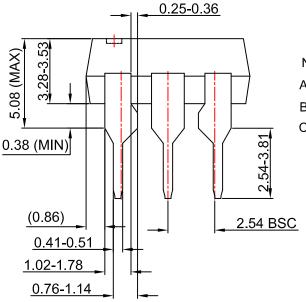


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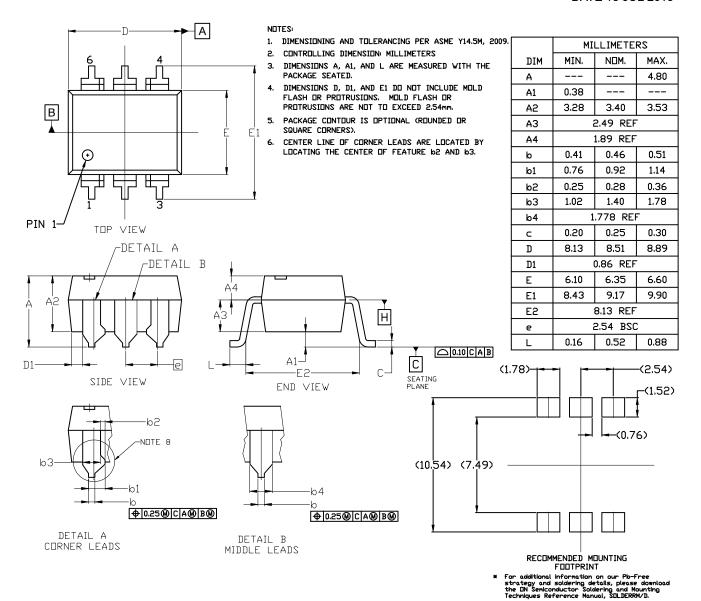
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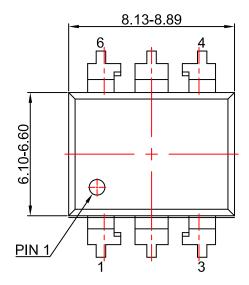
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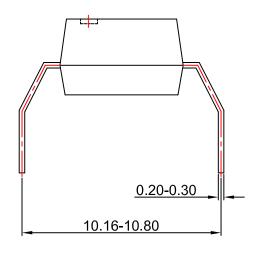
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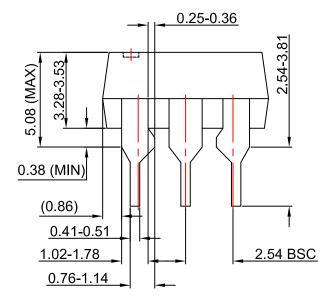


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